

## N-Channel Super Junction Power MOSFET III

### General Description

The series of devices use advanced trench gate super junction technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

### Features

- Optimized body diode reverse recovery performance
- Low on-resistance and low conduction losses
- Small package
- Ultra Low Gate Charge cause lower driving requirements
- 100% Avalanche Tested
- ROHS compliant

### Application

- Power factor correction (PFC)
- Switched mode power supplies (SMPS)
- Uninterruptible Power Supply (UPS)
- LLC Half-bridge

$V_{DS}$	650	V
$R_{DS(ON)TYP}$	110	m $\Omega$
$I_D$	28	A

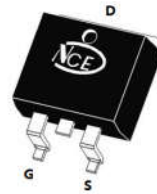


Schematic diagram

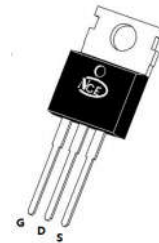
✧ Intrinsic fast-recovery body diode

### Package Marking And Ordering Information

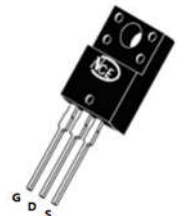
Device	Device Package	Marking
NCE65TF130D	TO-263	NCE65TF130D
NCE65TF130	TO-220	NCE65TF130
NCE65TF130F	TO-220F	NCE65TF130F



TO-263



TO-220



TO-220F

Table 1. Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ )

Parameter	Symbol	NCE65TF130D NCE65TF130	NCE65TF130F	Unit
Drain-Source Voltage ( $V_{GS}=0V$ )	$V_{DS}$	650		V
Gate-Source Voltage ( $V_{DS}=0V$ ) AC ( $f>1$ Hz)	$V_{GS}$	$\pm 30$		V
Continuous Drain Current at $T_c=25^\circ\text{C}$	$I_{D(DC)}$	28	28*	A
Continuous Drain Current at $T_c=100^\circ\text{C}$	$I_{D(DC)}$	18	18*	A
Pulsed drain current (Note 1)	$I_{DM(pluse)}$	112	112*	A
Maximum Power Dissipation ( $T_c=25^\circ\text{C}$ )	$P_D$	260	35	W
Derate above $25^\circ\text{C}$		2.08	0.28	W/ $^\circ\text{C}$
Single pulse avalanche energy (Note 2)	$E_{AS}$	676		mJ
Avalanche current (Note 1)	$I_{AR}$	5.2		A
Repetitive Avalanche energy, $t_{AR}$ limited by $T_{jmax}$ (Note 1)	$E_{AR}$	3.2		mJ

Parameter	Symbol	NCE65TF130D NCE65TF130	NCE65TF130F	Unit
Drain Source voltage slope, $V_{DS} \leq 480V$ ,	dv/dt	50		V/ns
Reverse diode dv/dt, $V_{DS} \leq 480V, I_{SD} < I_D$	dv/dt	50		V/ns
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55...+150		°C

\* limited by maximum junction temperature

**Table 2. Thermal Characteristic**

Parameter	Symbol	NCE65TF130D NCE65TF130	NCE65TF130F	Unit
Thermal Resistance, Junction-to-Case (Maximum)	$R_{thJC}$	0.48	3.57	°C /W
Thermal Resistance, Junction-to-Ambient (Maximum)	$R_{thJA}$	62	80	°C /W

**Table 3. Electrical Characteristics (TA=25°C unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>On/off states</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	650			V
Zero Gate Voltage Drain Current( $T_c=25^\circ C$ )	$I_{DSS}$	$V_{DS}=650V, V_{GS}=0V$			3	$\mu A$
Zero Gate Voltage Drain Current( $T_c=125^\circ C$ )	$I_{DSS}$	$V_{DS}=650V, V_{GS}=0V$			100	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$			$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	3	3.5	4	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=14A$		110	140	m $\Omega$
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=50V, V_{GS}=0V,$		2070		pF
Output Capacitance	$C_{oss}$	$F=1.0MHz$		120		pF
Effective output capacitance, energy related	$C_{o(er)}$	$V_{GS}=0V, V_{DS}=0...480V$		60		pF
Effective output capacitance, time related	$C_{o(tr)}$	$I_D=constant, V_{GS}=0V$ $V_{DS}=0...480V$		311		pF
Total Gate Charge	$Q_g$	$V_{DS}=480V, I_D=28A,$ $V_{GS}=10V$		37.5		nC
Gate-Source Charge	$Q_{gs}$			13		nC
Gate-Drain Charge	$Q_{gd}$			11.5		nC
<b>Switching times</b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=380V, I_D=14A,$ $R_G=2.3\Omega, V_{GS}=10V$		14		nS
Turn-on Rise Time	$t_r$			12		nS
Turn-Off Delay Time	$t_{d(off)}$			65		nS
Turn-Off Fall Time	$t_f$			11		nS
<b>Source- Drain Diode Characteristics</b>						
Source-drain current(Body Diode)	$I_{SD}$	$T_c=25^\circ C$			28	A
Pulsed Source-drain current(Body Diode)	$I_{SDM}$				112	A
Forward On Voltage	$V_{SD}$	$T_j=25^\circ C, I_{SD}=28A, V_{GS}=0V$		0.9	1.2	V
Reverse Recovery Time	$t_{rr}$	$T_j=25^\circ C, I_F=14A, di/dt=100A/\mu s$		190		nS
Reverse Recovery Charge	$Q_{rr}$			2		$\mu C$
Peak Reverse Recovery Current	$I_{rrm}$			21		A

Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

2.  $T_j=25^\circ C, V_{DD}=50V, V_G=10V, R_G=25\Omega$

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

Figure1. Safe operating area

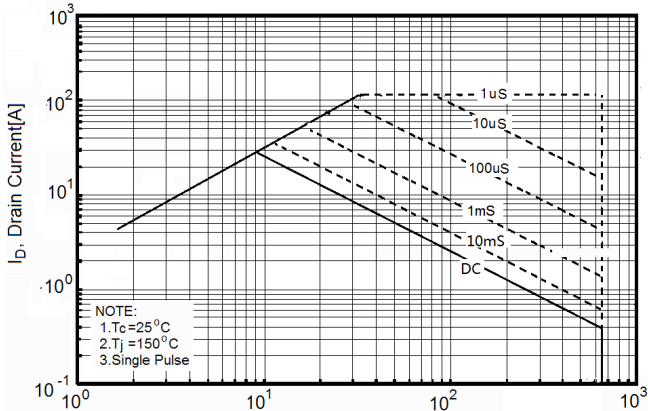


Figure2. Safe operating area for TO-220F

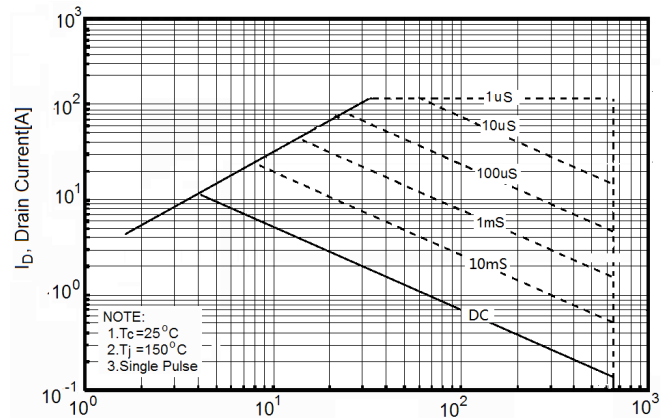


Figure3. Source-Drain Diode Forward Voltage

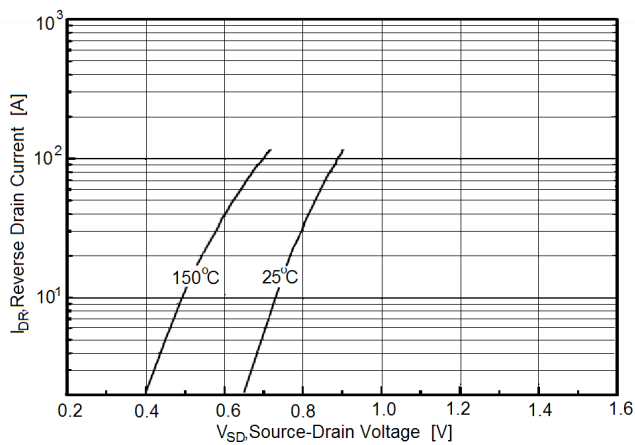


Figure4. Output characteristics

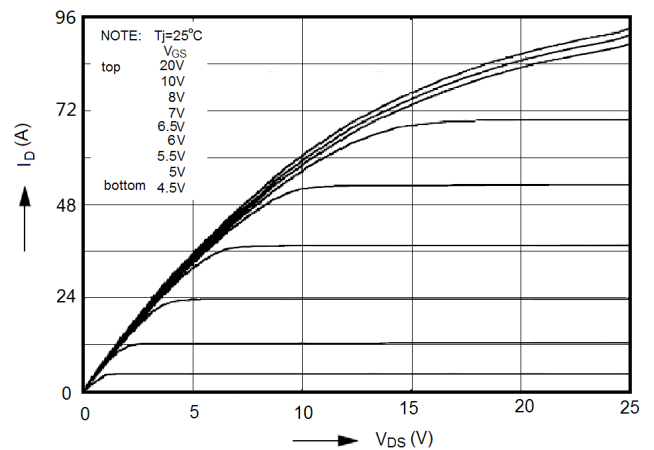


Figure5. Transfer characteristics

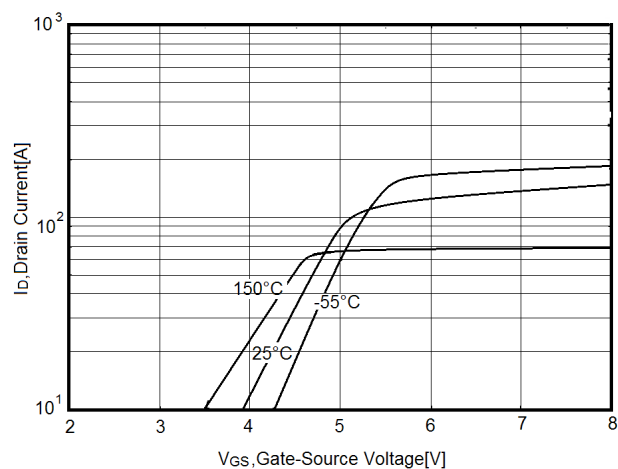
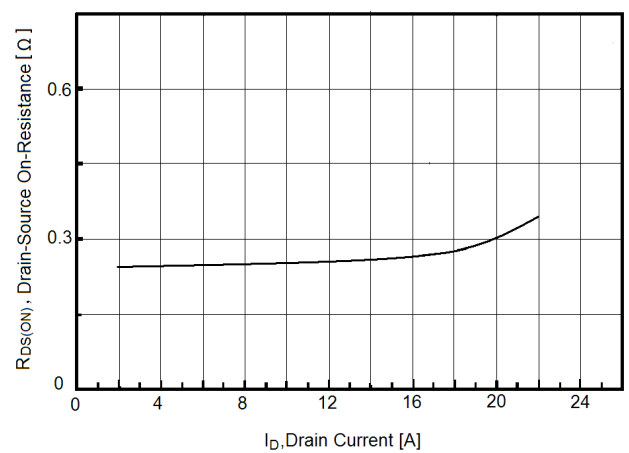
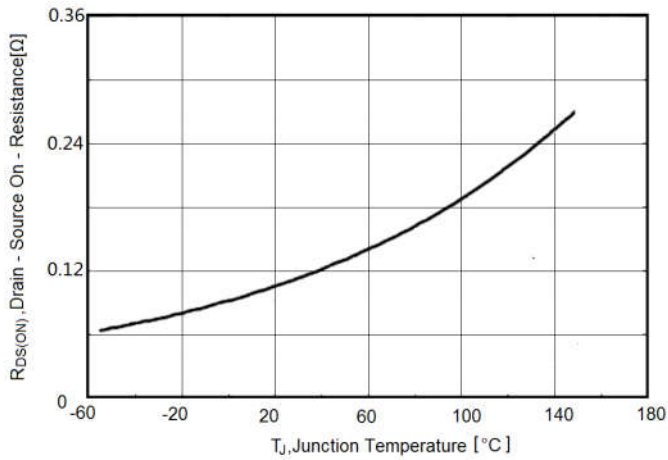


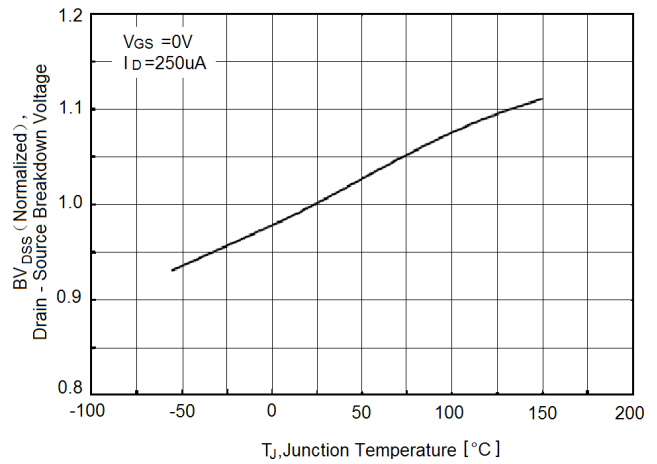
Figure6. Static drain-source on resistance



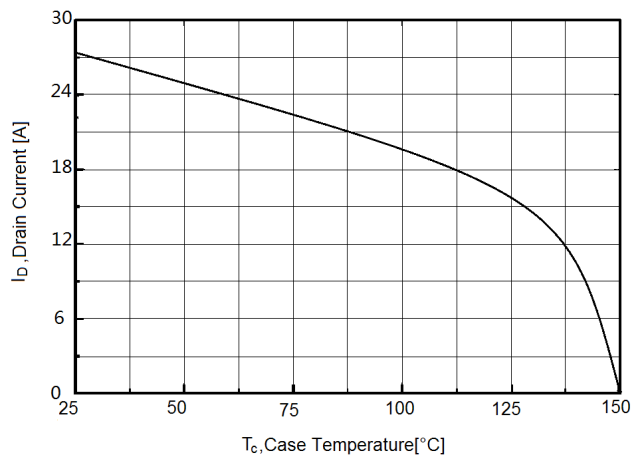
**Figure7.  $R_{DS(ON)}$  vs Junction Temperature**



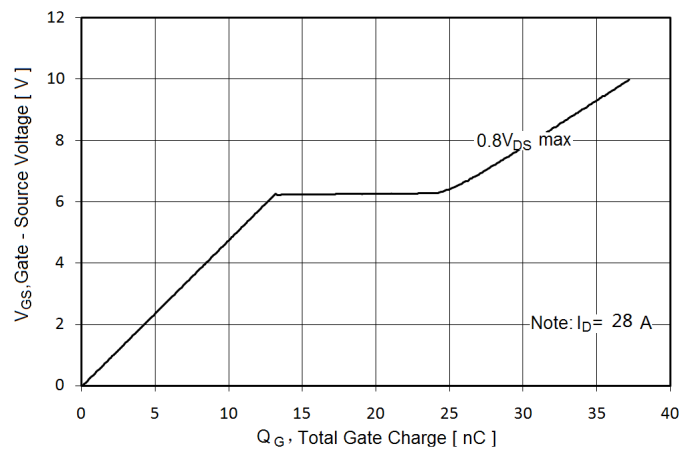
**Figure8.  $BV_{DSS}$  vs Junction Temperature**



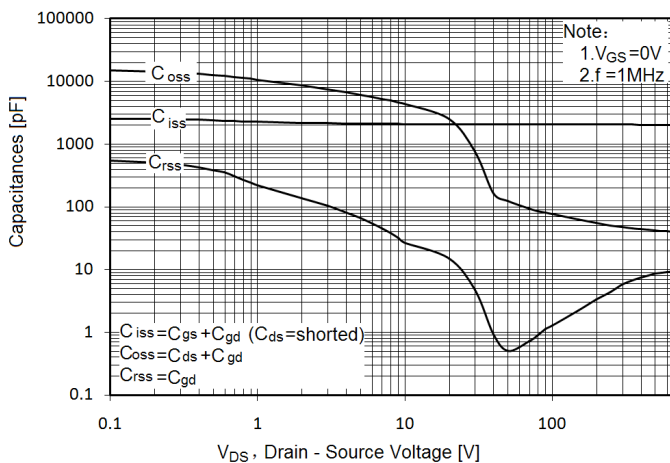
**Figure9. Maximum  $I_D$  vs Junction Temperature**



**Figure10. Gate charge waveforms**



**Figure11. Capacitance**



**Figure12. Transient Thermal Impedance**

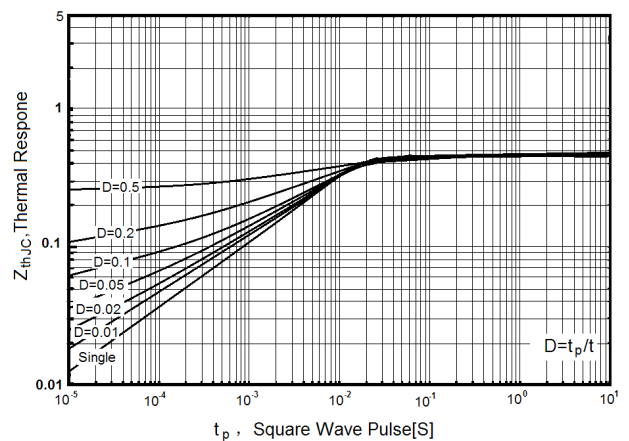
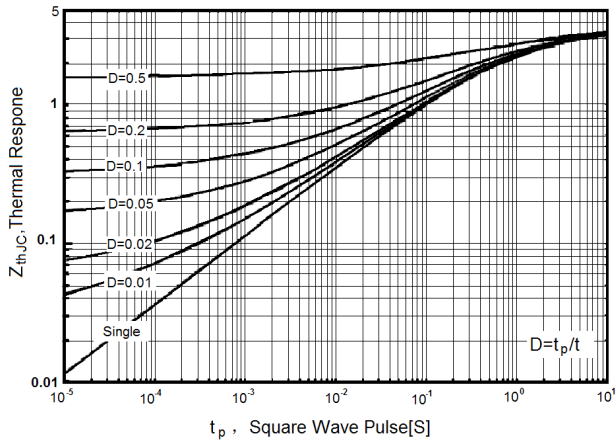


Figure13. Transient Thermal Impedance for TO-220F



## Test circuit

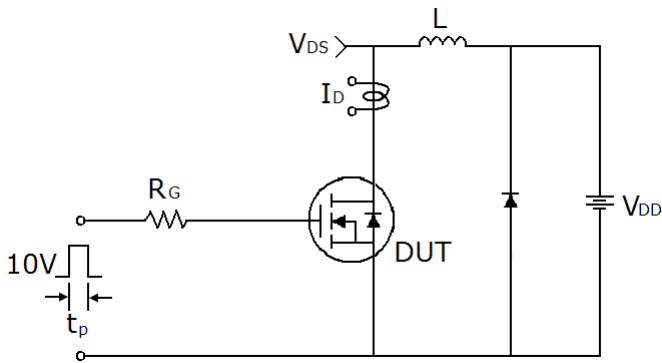
### 1) Gate charge test circuit & Waveform



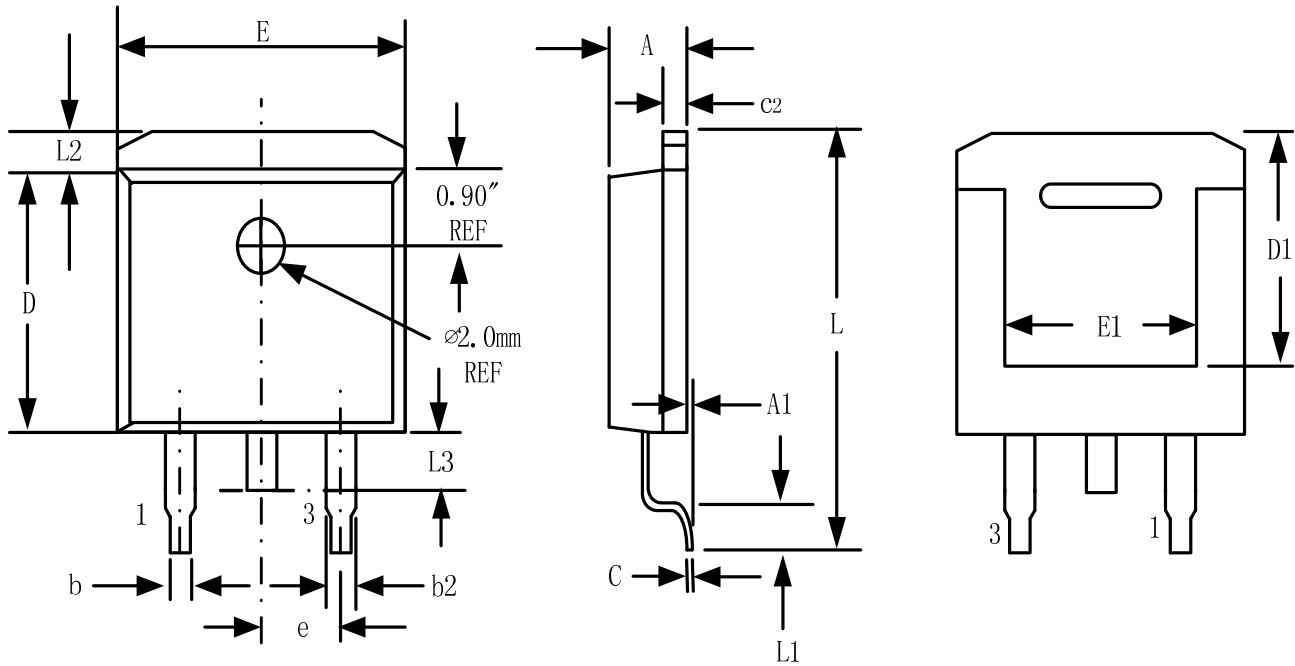
### 2) Switch Time Test Circuit:



### 3) Unclamped Inductive Switching Test Circuit & Waveforms



## TO-263-3L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.57	0.170	0.180
A1	-	0.25		0.010
b	0.71	0.94	0.028	0.037
b2	1.15	1.40	0.045	0.055
c	0.46	0.61	0.018	0.024
c2	1.22	1.40	0.048	0.055
D	8.89	9.40	0.350	0.370
D1	8.01	8.23	0.315	0.324
E	10.04	10.28	0.395	0.405
E1	7.88	8.08	0.310	0.318
e	2.54 BSC		0.100 BSC	
L	14.73	15.75	0.580	0.620
L1	2.29	2.79	0.090	0.110
L2	1.15	1.39	0.045	0.055
L3	1.27	1.77	0.050	0.070

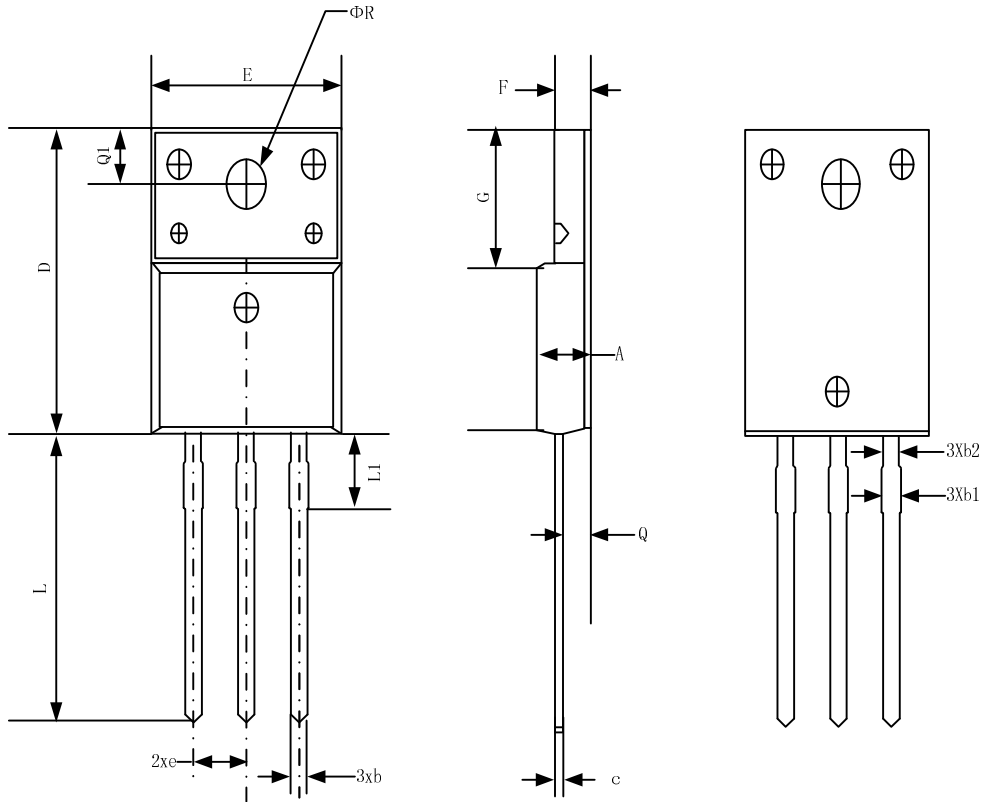
## TO-220-3L-C Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.400	4.600	0.173	0.181
A1	2.250	2.550	0.089	0.100
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.330	0.650	0.013	0.026
c1	1.200	1.400	0.047	0.055
D	9.910	10.250	0.390	0.404
E	8.9500	9.750	0.352	0.384
E1	12.650	12.950	0.498	0.510
e	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
F	2.650	2.950	0.104	0.116
H	7.900	8.100	0.311	0.319
h	0.000	0.300	0.000	0.012
L	12.900	13.400	0.508	0.528
L1	2.850	3.250	0.112	0.128
V	7.500 REF.		0.295 REF.	
Φ	3.400	3.800	0.134	0.150



## TO-220F Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.50	4.83	0.18	0.19
b	0.70	0.91	0.03	0.04
b1	1.20	1.47	0.05	0.06
b2	1.10	1.38	0.04	0.05
c	0.45	0.63	0.02	0.02
D	15.67	16.07	0.62	0.63
e	2.54 BSC		0.10 BSC	
E	9.96	10.36	0.39	0.41
F	2.34	2.74	0.09	0.11
G	6.48	6.90	0.26	0.27
L	12.68	13.30	0.50	0.52
L1	3.13	3.50	0.12	0.14
Q	2.56	2.93	0.10	0.12
Q1	3.20	3.40	0.13	0.13
ΦR	3.08	3.28	0.12	0.13



# NCE65TF130D,NCE65TF130,NCE65TF130F

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